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Kind regards,

Team Nexperia



# PMEG2005CT

# 500 mA low V<sub>F</sub> dual MEGA Schottky barrier rectifier Rev. 2 — 22 June 2010 Product

Product data sheet

## **Product profile**

#### 1.1 General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier in common cathode configuration with an integrated guard ring for stress protection, encapsulated in a SOT23 (TO-236AB) small Surface-Mounted Device (SMD) plastic package.

## 1.2 Features and benefits

- Average forward current: I<sub>F(AV)</sub> ≤ 0.5 A
   AEC-Q101 qualified
- Reverse voltage: V<sub>R</sub> ≤ 20 V
- Low forward voltage

- Small SMD plastic package

## 1.3 Applications

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch Mode Power Supply (SMPS)
- Reverse polarity protection
- High-speed switching
- Low power consumption applications

## 1.4 Quick reference data

Table 1. Quick reference data  $T_i = 25$  °C unless otherwise specified.

J	· ·					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						
I <sub>F(AV)</sub>	average forward current	square wave; $\delta = 0.5$ ; f = 20  kHz				
		$T_{amb} \le 100  ^{\circ}C$	[1] -	-	0.5	Α
		$T_{sp} \le 130  ^{\circ}C$	-	-	0.5	Α
$V_R$	reverse voltage		-	-	20	V
$V_{F}$	forward voltage	$I_F = 0.5 A$	-	360	390	mV
I <sub>R</sub>	reverse current	$V_R = 20 V$	-	30	200	μΑ

<sup>[1]</sup> Device mounted on a ceramic Printed-Circuit Board (PCB), Al<sub>2</sub>O<sub>3</sub>, standard footprint.



## 2. Pinning information

Table 2. Pinning

Table 2.	riiiiiig		
Pin	Description	Simplified outline	Graphic symbol
1	anode (diode 1)	—-	
2	anode (diode 2)	3	3
3	common cathode	1 2	1 2 006aaa438

## 3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PMEG2005CT	-	plastic surface-mounted package; 3 leads	SOT23

## 4. Marking

Table 4. Marking codes

Type number	Marking code <sup>[1]</sup>
PMEG2005CT	P8*

<sup>[1] \* = -:</sup> made in Hong Kong

## 5. Limiting values

PMEG2005CT

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per diode					
V <sub>R</sub>	reverse voltage	T <sub>j</sub> = 25 °C	-	20	V
I <sub>F(AV)</sub>	average forward current	square wave; $\delta$ = 0.5; $f$ = 20 kHz			
		T <sub>amb</sub> ≤ 100 °C	<u>[1]</u> -	0.5	Α
		T <sub>sp</sub> ≤ 130 °C	-	0.5	Α
I <sub>FRM</sub>	repetitive peak forward current	$t_p \leq 1 \text{ ms;} \\ \delta \leq 0.25$	-	3.9	Α
I <sub>FSM</sub>	non-repetitive peak forward current	square wave; $t_p = 8 \text{ ms}$	[2] _	10	Α
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<sup>\* =</sup> p: made in Hong Kong

<sup>\* =</sup> t: made in Malaysia

<sup>\* =</sup> W: made in China

 Table 5.
 Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per device;	one diode loaded				
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25  ^{\circ}C$	[3] _	330	mW
			[4] _	400	mW
			[1] -	460	mW
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		<b>–55</b>	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

<sup>[1]</sup> Device mounted on a ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint.

## 6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per device:	one diode loaded					
· -ui(j-a)	thermal resistance from	in free air	<u>[1]</u>			
	junction to ambient		[2] _	-	375	K/W
			[3]	-	310	K/W
			[4] _	-	270	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point		<u>[5]</u> _	-	60	K/W

<sup>[1]</sup> For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P<sub>R</sub> are a significant part of the total power losses.

<sup>[2]</sup>  $T_j = 25$  °C prior to surge.

<sup>3]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

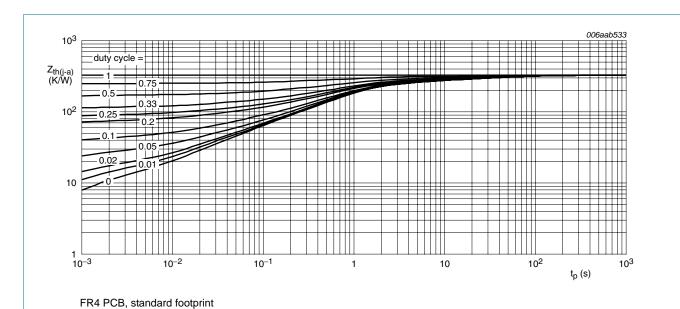
<sup>[4]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.

<sup>[2]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

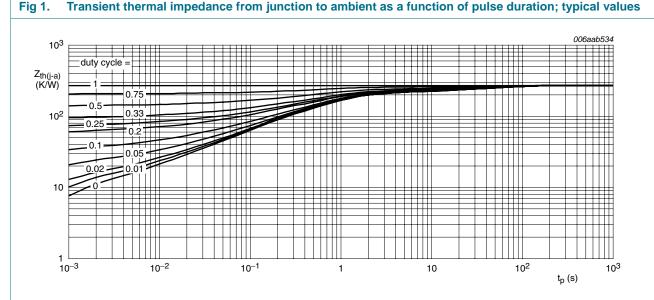
<sup>[3]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.

<sup>[4]</sup> Device mounted on a ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint.

<sup>[5]</sup> Soldering point of cathode tab.

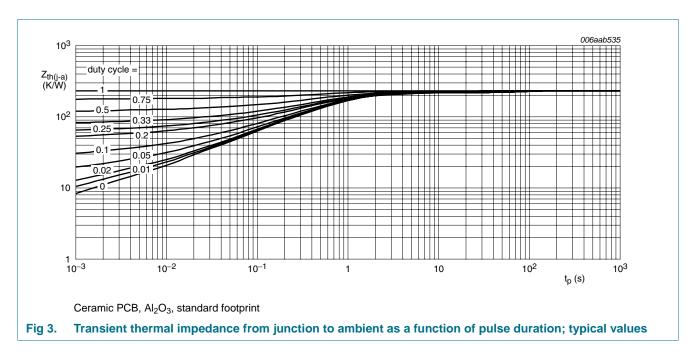


Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, mounting pad for cathode 1 cm<sup>2</sup>

Transient thermal impedance from junction to ambient as a function of pulse duration; typical values Fig 2.



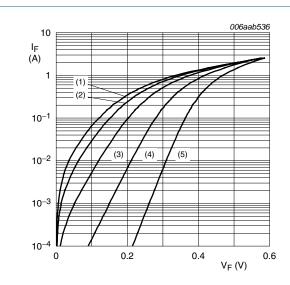
## 7. Characteristics

Table 7. Characteristics

 $T_i = 25$  °C unless otherwise specified.

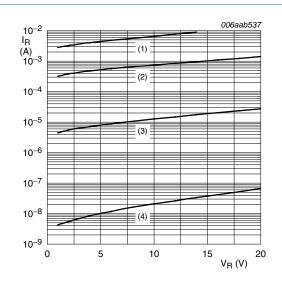
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per device						
$V_{F}$	forward voltage	$I_F = 0.1 \text{ mA}$	-	95	130	mV
		I <sub>F</sub> = 1 mA	-	155	190	mV
		I <sub>F</sub> = 10 mA	-	215	240	mV
		I <sub>F</sub> = 100 mA	-	285	330	mV
		I <sub>F</sub> = 500 mA	-	360	390	mV
I <sub>R</sub>	reverse current	V <sub>R</sub> = 10 V	-	11	40	μΑ
		V <sub>R</sub> = 20 V	-	30	200	μΑ
C <sub>d</sub>	diode capacitance	$V_R = 1 V$ ; $f = 1 MHz$	-	66	80	pF
t <sub>rr</sub>	reverse recovery time		<u>[1]</u> -	22	-	ns

<sup>[1]</sup> When switched from  $I_F$  = 10 mA to  $I_R$  = 10 mA;  $R_L$  = 100  $\Omega;$  measured at  $I_R$  = 1 mA.



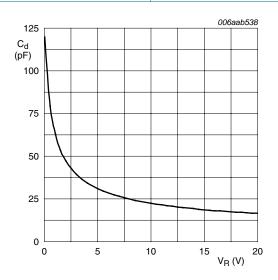
- (1)  $T_j = 150 \,^{\circ}\text{C}$
- (2)  $T_i = 125 \, ^{\circ}C$
- (3)  $T_j = 85 \,^{\circ}C$
- (4)  $T_j = 25 \, ^{\circ}C$
- (5)  $T_i = -40 \, ^{\circ}C$

Fig 4. Forward current as a function of forward voltage; typical values



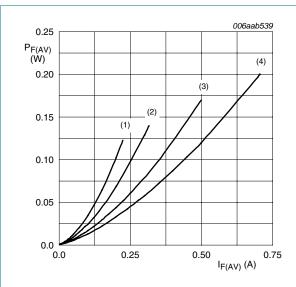
- (1)  $T_j = 125 \, ^{\circ}C$
- (2)  $T_j = 85 \, ^{\circ}C$
- (3)  $T_j = 25 \, ^{\circ}C$
- (4)  $T_j = -40 \, ^{\circ}C$

Fig 5. Reverse current as a function of reverse voltage; typical values



f = 1 MHz; T<sub>amb</sub> = 25 °C

Fig 6. Diode capacitance as a function of reverse voltage; typical values



T<sub>i</sub> = 150 °C

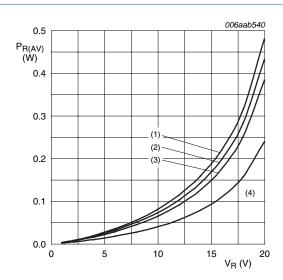
(1) 
$$\delta = 0.1$$

(2) 
$$\delta = 0.2$$

(3) 
$$\delta = 0.5$$

(4)  $\delta = 1$ 

Fig 7. Average forward power dissipation as a function of average forward current; typical values



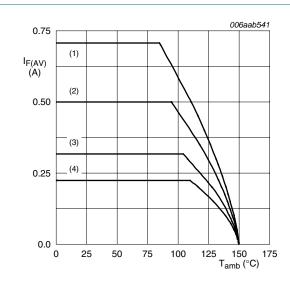
(1) 
$$\delta = 1$$

(2) 
$$\delta = 0.9$$

(3) 
$$\delta = 0.8$$

(4) 
$$\delta = 0.5$$

Fig 8. Average reverse power dissipation as a function of reverse voltage; typical values



FR4 PCB, standard footprint

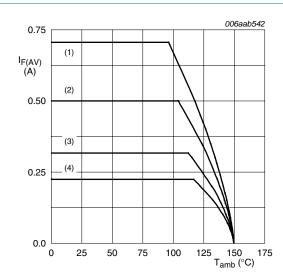
(1)  $\delta = 1$ ; DC

(2)  $\delta = 0.5$ ; f = 20 kHz

(3)  $\delta = 0.2$ ; f = 20 kHz

(4)  $\delta = 0.1$ ; f = 20 kHz

Fig 9. Average forward current as a function of ambient temperature; typical values



FR4 PCB, mounting pad for cathode 1 cm<sup>2</sup>

(1)  $\delta = 1$ ; DC

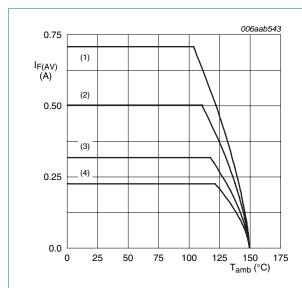
(2)  $\delta = 0.5$ ; f = 20 kHz

(3)  $\delta = 0.2$ ; f = 20 kHz

(4)  $\delta = 0.1$ ; f = 20 kHz

Fig 10. Average forward current as a function of ambient temperature; typical values

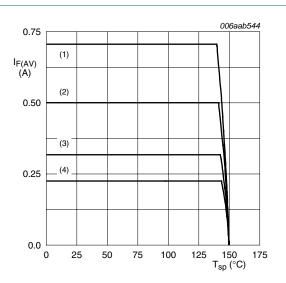
PMEG2005CT



Ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint

- (1)  $\delta = 1$ ; DC
- (2)  $\delta = 0.5$ ; f = 20 kHz
- (3)  $\delta = 0.2$ ; f = 20 kHz
- (4)  $\delta = 0.1$ ; f = 20 kHz

Fig 11. Average forward current as a function of ambient temperature; typical values



- (1)  $\delta = 1$ ; DC
- (2)  $\delta = 0.5$ ; f = 20 kHz
- (3)  $\delta = 0.2$ ; f = 20 kHz
- (4)  $\delta = 0.1$ ; f = 20 kHz

Fig 12. Average forward current as a function of solder point temperature; typical values

## 8. Test information

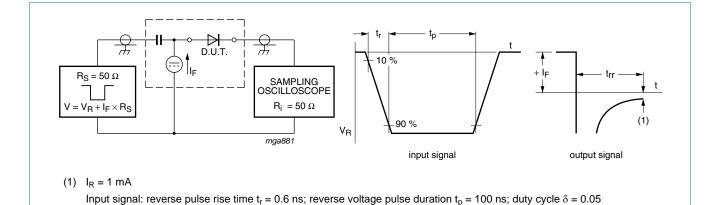
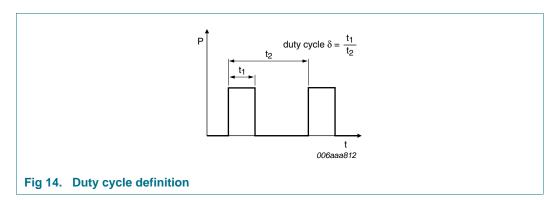


Fig 13. Reverse recovery time test circuit and waveforms

Oscilloscope: rise time  $t_r = 0.35$  ns

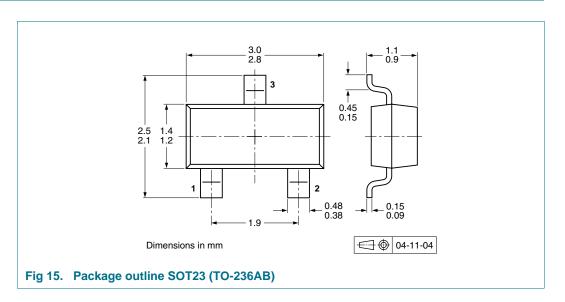


The current ratings for the typical waveforms as shown in Figure 9, 10, 11 and 12 are calculated according to the equations:  $I_{E(AV)} = I_M \times \delta$  with  $I_M$  defined as peak current,  $I_{RMS} = I_{F(AV)}$  at DC, and  $I_{RMS} = I_M \times \sqrt{\delta}$  with  $I_{RMS}$  defined as RMS current.

## 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

## 9. Package outline



## 10. Packing information

Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	 Packing q	uantity
			3000	10000
PMEG2005CT	SOT23	4 mm pitch, 8 mm tape and reel	-215	-235

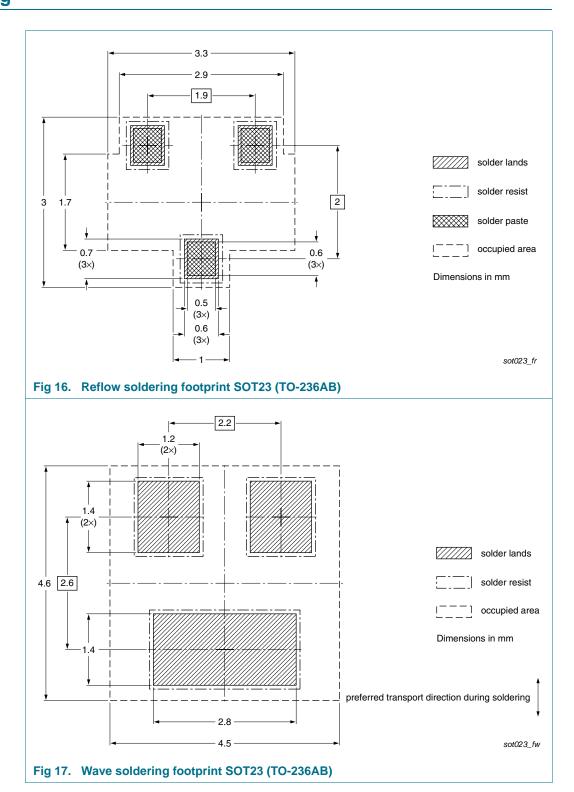
[1] For further information and the availability of packing methods, see Section 14.

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## 11. Soldering





## 12. Revision history

## Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PMEG2005CT v.2	20100622	Product data sheet	-	PMEG2005CT_1
Modifications:	• Table 2 "Pinr	ning": Graphic symbol amende	d	
	<ul> <li>Section 13 "L</li> </ul>	<u>egal information"</u> : updated		
PMEG2005CT_1	20090604	Product data sheet	-	-

## 13. Legal information

#### 13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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# PMEG2005CT

## 500 mA low V<sub>F</sub> dual MEGA Schottky barrier rectifier

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